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## AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application.

1. (currently amended) An electromagnetic radiation sensor assembly, comprising:

a heat bath;

an antenna element for receiving radiant electromagnetic energy;

a thermally responsive absorber element coupled to the antenna element and including means for absorbing and detecting radiant electromagnetic energy received by said antenna element;

an intermediate stage for thermally isolating the absorber element from the heat bath, said intermediate stage including at least two first and at least two second thermal isolation members each having a predetermined thermal conductance interconnecting the absorber element to the intermediate stage and the intermediate stage to the heat bath, the first thermal isolation members being located between the absorber element and the intermediate stage and the second thermal isolation members being located between the intermediate stage and the heat bath;

an electro-thermal feedback circuit incorporated into the intermediate stage for reducing the thermal conductivity between the absorber element and the heat bath by causing the temperature of the intermediate stage to converge to the temperature of the absorber element when detecting electromagnetic radiation, thus effectively causing the thermal conductance of the first thermal isolation members to attain a minimum conductance value and thereby improve the sensitivity of the radiation sensor towards the radiation limit; and

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wherein the electro-thermal feedback circuit includes a heat generating amplifier including a bipolar transistor integrated with the intermediate stage and means for detecting the temperature difference between the absorber element and the intermediate stage and generating an output voltage signal dependent on the received electromagnetic radiation to control the power generated by the amplifier, wherein the heat generated by the transistor included in the amplifier itself directly heats the intermediate stage in response to said temperature difference signal so as to <u>equalize equality</u> the temperature between the absorber element and the intermediate stage.

- 2. (original) A sensor assembly according to claim 1 wherein said sensor assembly comprises a two-tier device and wherein said antenna element, said absorber element and said intermediate stage comprises substantially coplanar elements located above the heat bath.
- 3. (original) A sensor assembly according to claim 1 wherein said antenna element is located on an upper outer surface of said heat bath.
- 4. (original) A sensor assembly according to claim 1 wherein the assembly comprises an x-y sensor assembly including x-y address readout circuits, and wherein said heat bath, said antenna element, said absorber element and said intermediate stage form a single pixel addressed by the x-y address readout circuits.
- 5. (original) A sensor assembly according to claim 1 wherein the spectral response of at least one of the elements including said absorber element and said antenna element is adjusted to operate in a predetermined region of the

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electromagnetic spectrum, including at least the infrared region of the electromagnetic spectrum.

6. (currently amended) A sensor assembly according to claim 4\_5

wherein said predetermined region also includes millimeter wave region of the

electromagnetic spectrum.

7. (original) A sensor assembly according to claim 4 wherein said

absorber element comprises a bolometer.

8. (original) A sensor assembly according to claim 4 wherein said

absorber element includes resistor means and temperature sensor means,

wherein said resistor means is ac coupled to the antenna to receive and absorb

the electromagnetic energy, and said temperature sensor means is thermally

coupled to the resistor means to monitor its temperature.

9. (original) A sensor assembly according to claim 4 wherein said pixel is

fabricated in silicon.

10. (original) A sensor assembly according to claim 4 wherein a plurality

of said pixels are included in an array of pixels.

11. (original) A sensor assembly according to claim 2 wherein said

intermediate stage includes a support member and, wherein said support

member and said first and second isolation members form a bridge for

positioning the absorber element above the means providing a heat bath.

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12. (original) A sensor assembly according to claim 11 wherein said heat

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bath includes a substrate and an upper body portion on which the antenna

element is mounted, said upper body portion including a cavity over which the

intermediate stage and the absorber element are located.

13. (original) A sensor assembly according to claim 2 wherein said

amplifier including a bipolar transistor comprises an amplifier and wherein

said means for detecting the temperature difference includes first and second

diodes for respectively sensing the temperature difference between said

absorber element and said intermediate stage.

14. (currently amended) A sensor assembly according to claim 12\_13

wherein the first and second diodes are connected in back-to-back circuit

relationship and to the amplifier inputs.

15. (currently amended) A sensor assembly according to claim 3 wherein

said intermediate stage includes a centralized opening therein and wherein

said absorber element is located in said opening,

16. (original) An electromagnetic radiation sensor assembly, comprising:

an array of sensor pixels, each of said pixels including,

a heat sink in the form of a heat bath member,

an antenna element for receiving radiant electromagnetic energy

mounted on the heat bath member,

a thermally sensitive detector element coupled to the antenna element for

detecting the radiant electromagnetic energy,

an intermediate stage located between the detector element and the heat

bath member, and

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a support structure for the intermediate stage comprising at least two first thermal isolation members having a predetermined thermal and electrical conductance connecting the detector element to the intermediate stage and at least two second thermal isolation members having a predetermined thermal and electrical conductance connecting the intermediate stage to the common heat bath member;

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an electro-thermal feedback circuit in the intermediate stage for reducing the thermal conductivity between the detector element and the heat bath member by causing the temperature of the intermediate stage to converge to the temperature of the detector element in response to absorbed electromagnetic radiation, effectively causing the thermal conductance of the first thermal isolation members to attain a minimum conductance value and thereby improve thermal isolation and thus the sensitivity of the sensor element toward the radiation limit; and,

wherein the electro-thermal feedback circuit includes a heat generating amplifier, including a bipolar transistor, integrated with the intermediate stage as well as means for detecting the temperature difference between the detector element and the intermediate stage and generating a temperature difference signal for controlling the solid bipolar transistor and the heat generated thereby; and, wherein the heat generated by the bipolar transistor itself directly heats the intermediate stage in response to said temperature difference signal so as to converge the temperature of the intermediate stage to the temperature of the detector element.

17. (original) An electromagnetic assembly according to claim 16 wherein the antenna element, the detector element, the intermediate stage are substantially coplanar in a two tier assembly with the heat bath.

18. (original) A sensor assembly according to claim 16 wherein said detector element comprises a bolometer.

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19. (original) A sensor assembly according to claim 16 wherein the

spectral response of at least one of the elements including the detector element

and the antenna element is adjusted to operate in a predetermined region of

the electromagnetic spectrum.

20. (currently amended) A sensor assembly according to claim 18 19

wherein the predetermined region includes the infrared and/or millimeter wave

region of the electromagnetic spectrum.

21. (currently amended) An electromagnetic radiation sensor assembly,

comprising:

heat bath means;

antenna means located on an outer surface of the heat bath means for

receiving electromagnetic radiation;

heat absorber means for detecting electromagnetic radiation received by

the antenna means;

an intermediate stage located between the heat bath means and the heat

absorber means;

thermal isolation means located between the intermediate stage and the

heat bath means and the heat absorber means for thermally isolating the heat

absorber means from the heat bath means;

first means having a predetermined thermal and electrical conductance

for connecting the heat absorber means to the thermal isolation means, and

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second means having a predetermined thermal and electrical conductance for connecting the thermal isolation means to the heat bath means; and,

electro-thermal feedback circuit means incorporated into the thermal isolation means for reducing the thermal conductivity between the heat absorber means and the heat bath means by causing the temperature of the thermal isolation means to converge to the temperature of the heat absorber means when detecting electromagnetic radiation, effectively causing the thermal conductance of the first means for connecting to attain a minimum conductance value and thereby improve the sensitivity of the sensor assembly toward the radiation limit;

wherein the electro-thermal feedback circuit means includes heat generating bipolar transistor amplifier means integrated with the thermal isolation means, and means for detecting the temperature difference between the heat absorber means and the thermal isolation means and generating a temperature difference signal for controlling the power delivered by the bipolar transistor amplifier to the intermediate stage; and,

wherein the heat generated by the bipolar transistor amplifier means directly heats the thermal isolation means in response to said temperature difference signal so as to equalize the temperature between the heat absorber means and the intermediate stage.

22. (original) A sensor assembly according to claim 21 wherein said antenna means, said heat absorber means, and said thermal isolation means form a two-tier sensor assembly.

23 (new) An electromagnetic radiation sensor assembly, comprising: heat bath means;

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antenna means located on the heat bath means for receiving electromagnetic radiation;

heat absorber means for detecting electromagnetic radiation received by the antenna means;

an intermediate stage located between the heat bath means and the heat absorber means;

thermal isolation means located between the intermediate stage and the heat bath means and the heat absorber means for thermally isolating the heat absorber means from the heat bath means:

first means having a predetermined thermal and electrical conductance for connecting the heat absorber means to the thermal isolation means, and

second means having a predetermined thermal and electrical conductance for connecting the thermal isolation means to the heat bath means; and,

electro-thermal feedback circuit means incorporated into the thermal isolation means for reducing the thermal conductivity between the heat absorber means and the heat bath means by causing the temperature of the thermal isolation means to converge to the temperature of the heat absorber means when detecting electromagnetic radiation, effectively causing the thermal conductance of the first means for connecting to attain a minimum conductance value and thereby improve the sensitivity of the sensor assembly toward the radiation limit;

wherein the electro-thermal feedback circuit means includes heat generating amplifier means integrated with the thermal isolation means, and means for detecting the temperature difference between the heat absorber means and the thermal isolation means and generating a temperature difference signal for controlling the power delivered by the amplifier means to the intermediate stage; and,

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wherein the heat generated by the amplifier means directly heats the thermal isolation means in response to said temperature difference signal so as to equalize the temperature between the heat absorber means and the intermediate stage.

24. (new) A radiation sensor assembly according to claim 23 wherein the antenna means is located on an outer surface of the heat bath means.

25. (new) A sensor assembly according to claim 23 wherein said antenna means, said heat absorber means, and said thermal isolation means form a two-tier sensor assembly.

26. (new) An electromagnetic radiation sensor assembly, comprising: a heat bath;

an antenna element mounted on the heat bath for receiving incident radiant electromagnetic energy;

a thermally responsive absorber element coupled to the antenna element and including means for absorbing and detecting radiant electromagnetic energy received by said antenna element;

an intermediate stage for thermally isolating the absorber element from the heat bath, said intermediate stage including a support member and at least two first and at least two second thermal isolation members each having a predetermined thermal conductance interconnecting the absorber element to the intermediate stage and the intermediate stage to the heat bath;

wherein the support member and the first and second isolation members form a bridge for positioning the absorber element above the heat bath;

wherein the heat bath includes a substrate and an upper body portion on which the antenna element is mounted, the upper body portion including a cavity over which the intermediate stage and the absorber element are located;

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an electro-thermal feedback circuit incorporated into the intermediate stage for reducing the thermal conductivity between the absorber element and the heat bath by causing the temperature of the intermediate stage to converge to the temperature of the absorber element when detecting electromagnetic radiation, thus effectively causing the thermal conductance of the first thermal isolation members to attain a minimum conductance value and thereby improve the sensitivity of the radiation sensor towards the radiation limit; and

wherein the electro-thermal feedback circuit includes a heat generating amplifier and means for detecting the temperature difference between the absorber element and the intermediate stage and generating an output voltage signal dependent on the received electromagnetic radiation to control the power generated by the amplifier, wherein the heat generated by the amplifier itself directly heats the intermediate stage in response to said temperature difference signal so as to equalize the temperature between the absorber element and the intermediate stage.

- 27. (new) A radiation sensor assembly according to claim 26 wherein the heat generating amplifier includes semiconductor amplifier means.
- 28. (new) A radiation sensor assembly according to claim 27 wherein said semiconductor amplifier means includes at least one semiconductor amplifying device.

29. (new) A radiation sensor assembly according to claim 28 wherein said at least one semiconductor amplifying device comprises a transistor of a predetermined type integrated with the intermediate stage.

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30. (new) A radiation sensor assembly according to claim 29 wherein the transistor comprises a bipolar transistor.